

National Semiconductor

# LM567/LM567C Tone Decoder

### **General Description**

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the decoder. External components are used to independently set center frequency, bandwidth and output delay.

#### Features

- 20 to 1 frequency range with an external resistor
- Logic compatible output with 100 mA current sinking capability
- **Connection Diagrams** 
  - Metal Can Package OUTPUT я OUTPUT GND FII TER LOOP TIMING 2 6 FILTER CAPACITOR TIMING INPUT RESISTOR TI /H/6975-1

**Top View** 



Bandwidth adjustable from 0 to 14%

- High rejection of out of band signals and noise
- Immunity to false signals
- Highly stable center frequency
- Center frequency adjustable from 0.01 Hz to 500 kHz

#### **Applications**

- Touch tone decoding
- Precision oscillator
- Frequency monitoring and control
- Wide band FSK demodulation
- Ultrasonic controls
- Carrier current remote controls
- Communications paging decoders



Top View

Order Number LM567CM See NS Package Number M08A Order Number LM567CN See NS Package Number N08E

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Pin	9V
Power Dissipation (Note 1)	1100 mW
V <sub>8</sub>	15V
V <sub>3</sub>	-10V
V <sub>3</sub>	V <sub>4</sub> + 0.5V
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range LM567H LM567CH, LM567CM, LM567CN	-55°C to +125°C 0°C to +70°C

Soldering Information	
Dual-In-Line Package	
Soldering (10 sec.)	260°C
Small Outline Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Methods ar	nd Their Effect

see AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

## **Electrical Characteristics** AC Test Circuit, $T_A = 25^{\circ}C$ , $V^+ = 5V$

Parameters	Conditions	LM567			LM567C/LM567CM			11-14-
		Min	Тур	Max	Min	Тур	Max	Units
Power Supply Voltage Range		4.75	5.0	9.0	4.75	5.0	9.0	V
Power Supply Current Quiescent	R <sub>L</sub> = 20k		6	8		7	10	mA
Power Supply Current Activated	R <sub>L</sub> = 20k		11	13	0	12	15	mA
Input Resistance		18	20		15	20		kΩ
Smallest Detectable Input Voltage	$I_{L} = 100 \text{ mA}, f_{i} = f_{0}$		20	25		20	25	mVrms
Largest No Output Input Voltage	$I_{\rm C} = 100  {\rm mA}, f_{\rm i} = f_{\rm o}$	10	15		10	15		mVrms
Largest Simultaneous Outband Signal to Inband Signal Ratio			6			6		dB
Minimum Input Signal to Wideband Noise Ratio	B <sub>n</sub> = 140 kHz		6			-6		dB
Largest Detection Bandwidth		12	14	16	10	14	18	% of fo
Largest Detection Bandwidth Skew			1	2		2	3	% of fo
Largest Detection Bandwidth Variation with Temperature			±0.1			±0.1		%/°C
Largest Detection Bandwidth Variation with Supply Voltage	4.75 — 6.75V		±1	±2		±1	±5	%V
Highest Center Frequency		100	500		100	500		kHz
Center Frequency Stability (4.75-5.75V)	0 < T <sub>A</sub> < 70 -55 < T <sub>A</sub> < +125		35 ± 60 35 ± 140			35 ±60 35 ± 140		ppm/°C ppm/°C
Center Frequency Shift with Supply Voltage	4.75V – 6.75V 4.75V – 9V		0.5	1.0 2.0		0.4	2.0 2.0	%/V %/V
Fastest ON-OFF Cycling Rate			f <sub>o</sub> /20			f <sub>o</sub> /20		
Output Leakage Current	V <sub>8</sub> = 15V		0.01	25		0.01	25	μA
Output Saturation Voltage	$e_i = 25 \text{ mV}, I_8 = 30 \text{ mA}$ $e_i = 25 \text{ mV}, I_8 = 100 \text{ mA}$		0.2 0.6	0.4 1.0		0.2 0.6	0.4 1.0	v
Output Fall Time			30			30		ns
Output Rise Time			150			150		ns

Note 1: The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of 150°C/W, junction to ambient or 45°C/W, junction to case. For the DIP the device must be derated based on a thermal resistance of 160°C/W, junction to ambient or 45°C/W, because the device must be derated based on a thermal resistance of 160°C/W, junction to ambient or 45°C/W, because the device must be derated based on a thermal resistance of 160°C/W, junction to ambient.

Note 2: Refer to RETS567X drawing for specifications of military LM567H version.



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4-137





TL/H/6975-9

SIGNAL +5V

INPUT

 $f_i = 100 \text{ kHz} + 5V$ \*Note: Adjust for  $f_0 = 100 \text{ kHz}$ .

C3

C2